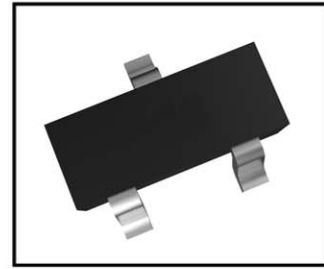


- PARTMARKING DETAIL –
 - BCX70G – AG
 - BCX70H – AH
 - BCX70J – AJ
 - BCX70K – AK



COMPLEMENTARY TYPE – BCX71

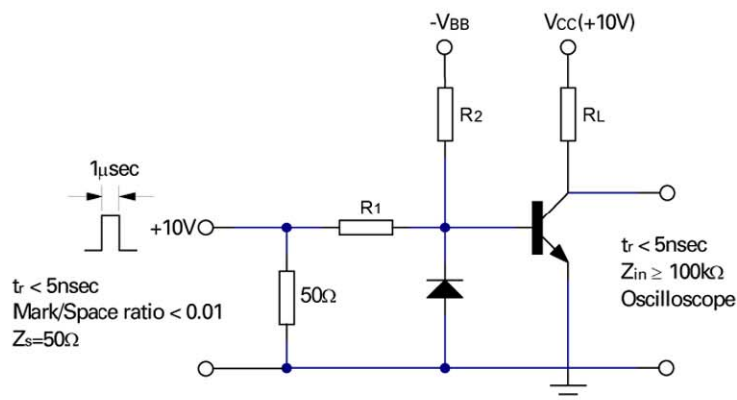
- **ABSOLUTE MAXIMUM RATINGS.**

PARAMETER	SYMBOL	VALUE	UNIT
Collector-Emitter Voltage	V_{CES}	45	V
Collector-Emitter Voltage	V_{CEO}	45	V
Emitter-Base Voltage	V_{EBO}	5	V
Continuous Collector Current	I_C	200	mA
Base Current	I_B	50	mA
Power Dissipation at $T_{amb}=25^{\circ}C$	P_{TOT}	330	mW
Operating and Storage Temperature Range	tj:tstg	-55 to +150	$^{\circ}C$

- **FOUR TERMINAL NETWORK DATA ($I_C=2mA, V_{CE}=5V, f=1kHz$)**

	h_{FE} Group G			h_{FE} Group H			h_{FE} Group J			h_{FE} Group K			
	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	Min.	Typ.	Max.	
h_{11e}	1.6	2.7	4.5	2.5	3.6	6.0	3.2	4.5	8.5	4.5	7.5	12	$k\Omega$
h_{12e}		1.5			2			2			3		10^{-4}
h_{21e}		200			260			330			520		
h_{22e}		18	30		24	50		30	60		50	100	μS

- **SWITCHING CIRCUIT**



PAGE NO



● **ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}C$ unless otherwise stated).**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS.	
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	45			V	$I_C=2mA$	
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	5			V	$I_{EBO}=1\mu A$	
Collector-Emitter Cut-off Current	I_{CES}			20 20	nA μA	$V_{CES}=45V$ $V_{CES}=45V$, $T_{amb}=150^{\circ}C$	
Emitter-Base Cut-Off Current	I_{EBO}			20	nA	$V_{EBO}=4V$	
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$		0.12 0.20	0.35 0.55	V V	$I_C=10mA, I_B=0.25mA$ $I_C=50mA, I_B=1.25mA$	
Base-Emitter Saturation Voltage	$V_{BE(SAT)}$	0.60 0.70	0.70 0.83	0.85 1.05	V V	$I_C=10mA, I_B=0.25mA$, $I_C=50mA, I_B=1.25mA$	
Base - Emitter Voltage	V_{BE}	0.55	0.52 0.65 0.78	0.75	V V V	$I_C=10\mu A, V_{CE}=5V$ $I_C=2mA, V_{CE}=5V$ $I_C=50mA, V_{CE}=1V$	
Static Forward Current Transfer Ratio	BCX70G	h_{FE}	120 50	78 170	220		$I_C=10\mu A, V_{CE}=5V$ $I_C=2mA, V_{CE}=5V$ $I_C=50mA, V_{CE}=1V$
	BCX70H	h_{FE}	20 180 70	145 250	310		$I_C=10\mu A, V_{CE}=5V$ $I_C=2mA, V_{CE}=5V$ $I_C=50mA, V_{CE}=1V$
	BCX70J	h_{FE}	40 250 90	220 350	460		$I_C=10\mu A, V_{CE}=5V$ $I_C=2mA, V_{CE}=5V$ $I_C=50mA, V_{CE}=1V$
	BCX70K	h_{FE}	100 380 100	300 500	630		$I_C=10\mu A, V_{CE}=5V$ $I_C=2mA, V_{CE}=5V$ $I_C=50mA, V_{CE}=1V$
Transition Frequency	f_T	125	250		MHz	$I_C=10mA, V_{CE}=5V$ $f=100MHz$	
Emitter-Base Capacitance	C_{ebo}		8		pF	$V_{EBO}=0.5V, f=1MHz$	
Collector-Base Capacitance	C_{cbo}			4.5	pF	$V_{CBO}=10V, f=1MHz$	
Noise Figure	N		2	6	dB	$I_C=0.2mA, V_{CE}=5V$ $R_G=2K\Omega, f=1KH$ $\Delta f=200Hz$	
Switching times:							
Delay Time	t_d		35		ns	$I_C:I_{B1}:I_{B2}=10:1:1mA$ $R_1=5K\Omega, R_2=5K\Omega$ $V_{BB}=3.6V, R_L=990\Omega$	
Rise Time	t_r		50		ns		
Turn-on Time	t_{on}		85	150	ns		
Storage Time	t_s		400		ns		
Fall Time	t_f		80		ns		
Turn-Off Time	t_{off}		480	800	ns		

*Measured under pulsed conditions. Pulse width=300 μs . Duty cycle
Spice parameter data is available upon request for this device

